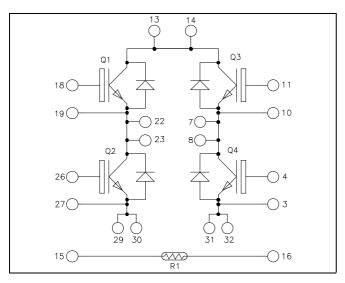
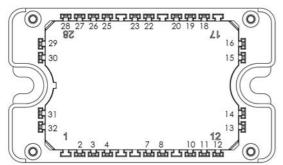


Full - Bridge Trench + Field Stop IGBT3 Power Module





All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

$V_{CES} = 1700V$ $I_C = 30A$ @ $T_C = 80$ °C

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Low stray inductance
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS Compliant

All ratings (a) $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (Per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		1700	V
$I_{\rm C}$	Continuous Collector Comment	$T_C = 25$ °C	45	
	Continuous Collector Current	$T_C = 80$ °C	30	Α
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	70	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Power Dissipation	$T_C = 25$ °C	210	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	60A@1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



Electrical Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				250	μΑ
V _{CE(sat)}	Collector Emitter saturation Voltage	- SE	$T_j = 25$ °C		2.0	2.4	V
			$T_j = 125$ °C		2.4		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1.5 \text{mA}$		5.2	5.8	6.4	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$, $V_{CE} = 25V$		2500		ъE
C_{res}	Reverse Transfer Capacitance	f = 1MHz		90		pF
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		100		
T_{r}	Rise Time	$V_{GE} = \pm 15V$		70		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 30A$		650		ns
T_{f}	Fall Time	$R_G = 18\Omega$		80		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		100		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$		70		
T _{d(off)}	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 30A$		750		ns
$T_{\rm f}$	Fall Time	$R_G = 18\Omega$		100		
E_{on}	Turn-on Switching Energy	110 1022		17		Т
E _{off}	Turn-off Switching Energy			15		mJ
R_{thJC}	Junction to Case Thermal Resistance				0.6	°C/W

$\label{eq:Reverse diode} Reverse \ diode \ ratings \ and \ characteristics \ (\text{Per diode})$

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage					1700	V
I_{RM}	Reverse Leakage Current	$V_R = 1700V$				250	μΑ
I_F	DC Forward Current		$T_C=50$ °C		50		A
$V_{\rm F}$	Diode Forward Voltage	$I_F = 50A$	$T_j = 25^{\circ}C$		1.8	2.2	V
V F		$V_{GE} = 0V$	$T_j = 125$ °C		1.9		V
	D		$T_j = 25^{\circ}C$		385		***
t_{rr}	Reverse Recovery Time	$I_F = 50A$	$T_j = 125$ °C		490	- In	ns
0	n n cl	$V_R = 900V$	$T_j = 25^{\circ}C$		14		C
Qп	Q _π Reverse Recovery Charge	di/dt	$T_j = 125$ °C		23		μC
Г	E _r Reverse Recovery Energy =800A/μs	$=800A/\mu s$	$T_j = 25$ °C		6		т
\mathcal{L}_{r}		$T_j = 125$ °C		12		mJ	
R_{thJC}	Junction to Case Thermal Resistance					0.7	°C/W



Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

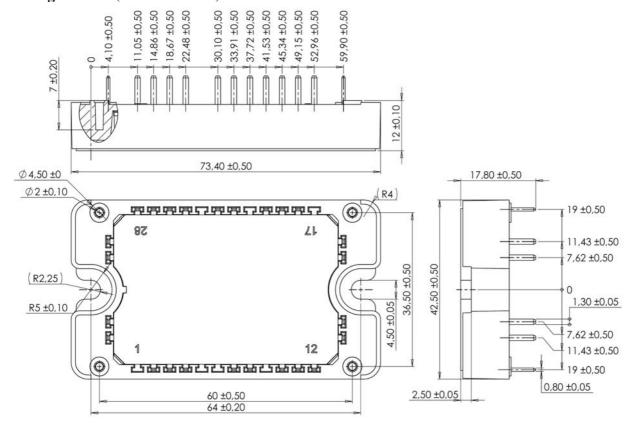
Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C	25°C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		$T_C=100$ °C		4		%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

Thermal and package characteristics

Symbol	l Characteristic				Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz					V
T_{J}	Operating junction temperature range			-40	150	
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C
T_{STG}	Storage Temperature Range			-40	125	
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight		•		110	g

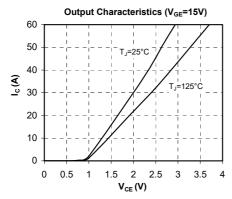
Package outline (dimensions in mm)

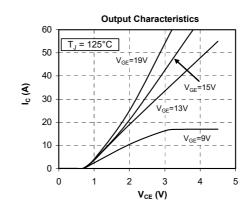


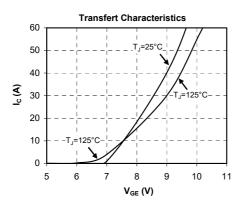
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

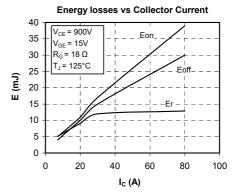


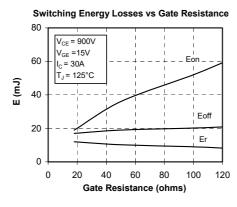
Typical Performance Curve

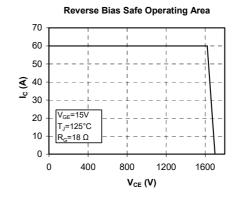


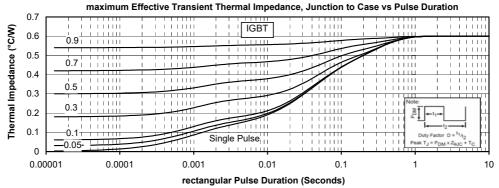




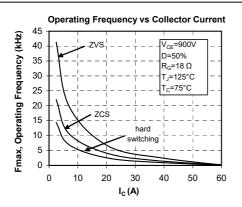


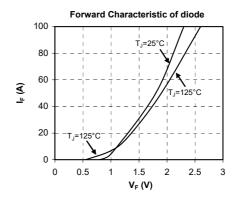


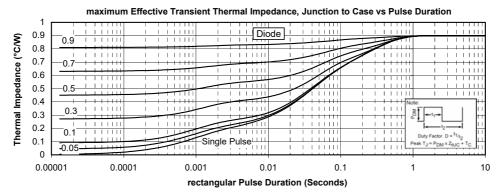














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